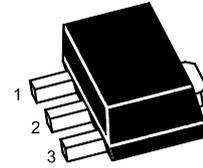


## Plastic-Encapsulate Transistors

### TRANSISTOR(PNP)

#### FEATURES

- Complementary to 2SC2883U
- Small Flat Package
- Audio Frequency Amplifier Application



1.Base 2.Collector 3.Emitter  
SOT-89 Plastic Package

#### MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-30	V
$V_{CEO}$	Collector-Emitter Voltage	-30	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	-1.5	A
$P_C$	Collector Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	250	$^\circ\text{C}/\text{W}$
$T_j$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~+150	$^\circ\text{C}$

#### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -1\text{mA}, I_E = 0$	-35			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -1\text{mA}, I_C = 0$	-5			V
Collector cut-off current	$I_{CBO}$	$V_{CB} = -30\text{V}, I_E = 0$			-100	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5\text{V}, I_C = 0$			-100	nA
DC current gain	$h_{FE}$	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$	100		320	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1.5\text{A}, I_B = -30\text{mA}$			-2	V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$			-1	V
Collector output capacitance	$C_{ob}$	$V_{CB} = -10\text{V}, I_E = 0, f = 1\text{MHz}$			50	pF
Transition frequency	$f_T$	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$		120		MHz

#### CLASSIFICATION OF $h_{FE}$

RANK	O	Y
RANGE	100 - 200	160 - 320
MARKING	HO	HY

### ■ Typical Characteristics

